## **Electronic supplementary information**

## MOF-derived lithiophilic CuO nanorod arrays for stable lithium metal anode

Lei Wei,<sup>a</sup> Li Li,<sup>a,b</sup> Teng Zhao, \*<sup>a</sup> Nanxiang Zhang,<sup>a</sup> Yuanyuan Zhao,<sup>a</sup> Feng Wu<sup>a,b</sup> and Renjie Chen \*<sup>a,b</sup>

- a. School of Materials Science & Engineering, Beijing Institute of Technology, Beijing 100081, China.
- b. Collaborative Innovation Center of Electric Vehicles in Beijing, Beijing 100081, China.

E-mail address: chenrj@bit.edu.cn (R. Chen); tz270@bit.edu.cn.

## **Supplementary figures**



**Fig. S1** Top view SEM images of planar Cu foil (a) front side (b) back side. (c) Digital photograph of planar Cu foil. (d) Cross-section SEM image of bare Cu foil. The thickness of Cu foil is about 10um. The inset of (a) and (b) show the high magnification images.



**Fig. S2** Opitical images of the color changes for bare Cu foil during the synthesis process.(a) Planar Cu. (b) Cu-TCNQ/CF. (c) CuO NAs/CF



**Fig. S3** SEM images of Cu-TCNQ/CF in a concentration of 0.5mM TCNQ acetonitrile solution with different reaction times. (a) 6h (b) 12h (c) 24h. SEM images of Cu-TCNQ/CF in a concentration of 1mM TCNQ acetonitrile solution with (d-e) 6h (f) 12h.



**Fig. S4** The selected area of TEM images about EDX mapping (a) and corresponding energy dispersive X-ray spectra (EDS) analysis (b) related to Fig. 2f.



**Fig. S5** (a) XRD pattern of planar Cu foil and Cu-TCNQ/CF with different concentration of TCNQ acetonitrile solution. (b) Enlarge pattern of the green dotted box.



Fig. S6 FT-IR spectra of Cu-TCNQ and CuO NAs.



Fig. S7 XPS and corresponding high resolution spectra of (a) CuO NAs/CF, (b) C1s (c) O1s, (d) Cu2p.



**Fig. S8** Cross-section SEM images of Li deposited on bare foil (a, b) and CuO NAs/CF (c, d). Before cycling (a, c), after 30<sup>th</sup> cycles (b, d).



**Fig. S9** Top view SEM images of Li deposited morphologies on CuO NAs/CF current collector with different amounts of Li deposition capacities at 1mA cm<sup>-2</sup>.(a, e) 0.2 mA h cm<sup>-2</sup>, (b, f) 0.5 mA h cm<sup>-2</sup>, (c, g) 1 mA h cm<sup>-2</sup>, (d, h) 2 mA h cm<sup>-2</sup>. The deposited Li were labeled by orange arrows.



Fig. S10 Top view SEM images of Li deposited on CuO NAs/CF current collector after 10 cycles.



**Fig. S11** Voltage-capacity curves of Li plating/stripping process on (a) CuO NAs/CF and (b) planar Cu foil current collector at 0.5 mA cm<sup>-2</sup> for 1 mA h cm<sup>-2</sup> of Li.



**Fig. S12** (a) The voltage-capacity curves of Li plating/stripping process at various cycles under 1  $mA/cm^2$  for a total capacity of 1 mA h cm<sup>-2</sup> Li. (b) Comparison of voltage hysteresis for 200 cycles at a current density of 1 mA cm<sup>-2</sup>.



**Fig. S13** (a) Voltage profiles of Li nucleation on Cu-TCNQ/CF current collector at a current density of 0.5 mA cm<sup>-2</sup>. (b) Coulombic efficiency of Cu-TCNQ/CF current collector at 0.5 mA cm<sup>-2</sup> with a total capacity of 1 mA h cm<sup>-2</sup>.



**Fig. S14** Coulombic efficiency of cells using the current collector that Cu-TCNQ/CF annealed in  $Ar_2$  with 1 mA h cm<sup>-2</sup> at a current density of (a) 0.5 mA cm<sup>-2</sup>, (b) 1 mA cm<sup>-2</sup>. (c) Voltage profiles of Li nucleation on the current collector at 0.5 mA cm<sup>-2</sup>. (d) The corresponding voltage-capacity

curves of Li plating/stripping process at 1 mA cm<sup>-2</sup> for 1 mA h cm<sup>-2</sup> of Li.



**Fig. S15** (a) Coulombic efficiency of CuO NAs/CF and planar Cu foil current collector with 1 mA h cm<sup>-2</sup> capacity at a current density of 3 mA cm<sup>-2</sup>. Coulombic efficiencies of two current collectors with a capacity of 2 mA h cm<sup>-2</sup> at (b) 0.5 mA cm<sup>-2</sup>, (c) 1 mA cm<sup>-2</sup>. (d) Coulombic efficiency of two current collectors with a capacity of 3 mA h cm<sup>-2</sup> at 1 mA cm<sup>-2</sup>.



**Fig. S16** Electrochemical impedance spectra (EIS) of Planar Cu foil and CuO NAs/CF after (a) 1st cycle (b) 30th cycles. (c) Equivalent circuit diagram for EIS plots in (a) and (b).

In addition, the electrochemical impedance was also fitted with Z-View software and the fitted parameters were shown in Table S1. It is shown that the bulk resistance ( $R_b$ ) increases after cycling. The charge transfer resistance ( $R_{ct}$ ) for the CuO NAs/CF is about 24.21  $\Omega$  after the 1st cycle and then decreases to 19.24  $\Omega$  after the 30th cycles, much lower than that of the planar Cu.

	Planar Cu			CuO NAs/CF		
	$R_b(\Omega)$	$R_{\text{SEI}}(\Omega)$	$R_{ct}(\Omega)$	$R_b(\Omega)$	$R_{\text{SEI}}(\Omega)$	$R_{ct}\left(\Omega ight)$
1 cycle	1.561	-	44.19	1.748	-	24.21
30 cycles	1.709	13.18	33.2	1.913	5.899	19.24

 Table S1. Electrochemical impedance fitted parameters for Figure S16 (a) and (b) with an equivalent circuit model.



Fig. S17 Voltage-time profiles of the symmetric cells for Li plating or stripping at 1 mA cm<sup>-2</sup> for 1 mA h cm<sup>-2</sup> with 4 mA h cm<sup>-2</sup> pre-deposited Li.



**Fig. S18** (a) The rate performance of LiFePO<sub>4</sub> full cells using planar Cu foil and CuO NAs/CF. (b) Charge-discharge curves of the Li-CuO NAs/CF||LFP full cells cycled at various C rates between 0.1 and 1C.



**Fig. S19** Typical galvanostatic charge-discharge profiles of the CuO NAs/CF||LFP and Li-Cu||LFP full cells at 0.5C.